

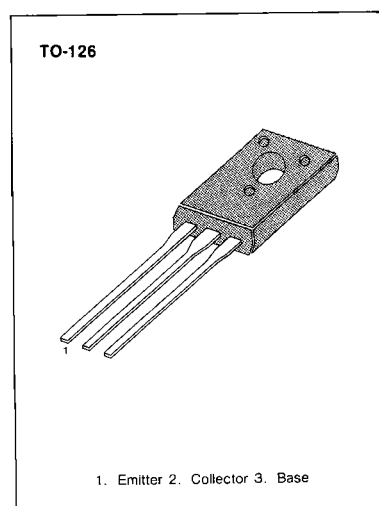
PNP Transistor KSB772 datasheet

AUDIO FREQUENCY POWER AMPLIFIER LOW SPEED SWITCHING

- Complement to KSD882

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current (DC)	I_C	-3	A
*Collector Current (Pulse)	I_C	-7	A
Base Current (DC)	I_B	-0.6	A
Collector Dissipation ($T_c = 25^\circ\text{C}$)	P_C	10	W
Collector Dissipation ($T_a = 25^\circ\text{C}$)	P_C	1	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55~150	$^\circ\text{C}$



- * $PW \leq 10\text{ms}$, Duty Cycle $\leq 50\%$

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Collector Cutoff Current	I_{CBO}	$V_{CB} = -30\text{V}, I_E = 0$			-1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = -3\text{V}, I_C = 0$			-1	μA
*DC Current Gain	h_{FE1}	$V_{CE} = -2\text{V}, I_C = -20\text{mA}$	30	220		
	h_{FE2}	$V_{CE} = -2\text{V}, I_C = -1\text{A}$	60	160	400	
*Collector Emitter Saturation Voltage	$V_{CE}(\text{sat})$	$I_C = -2\text{A}, I_B = -0.2\text{A}$		-0.3	-0.5	V
*Base Emitter Saturation Voltage	$V_{BE}(\text{sat})$	$I_C = -2\text{A}, I_B = -0.2\text{A}$		-1.0	-2.0	V
Current Gain Bandwidth Product	f_T	$V_{CE} = -5\text{V}, I_E = 0.1\text{A}$		80		MHz
Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0$ $f = 1\text{MHz}$		55		pF

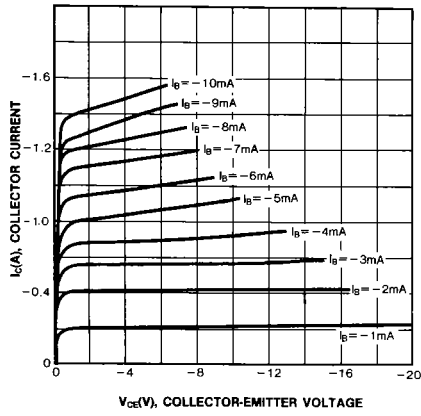
- * Pulse Test: $PW \leq 350\mu\text{s}$, Duty Cycle $\leq 2\%$

$h_{FE}(2)$ CLASSIFICATION

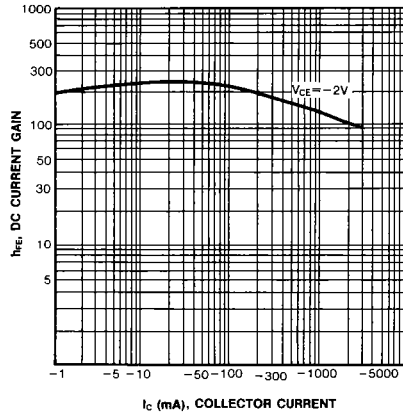
Classification	R	O	Y	G
$h_{FE}(2)$	60-120	100-200	160-320	200-400

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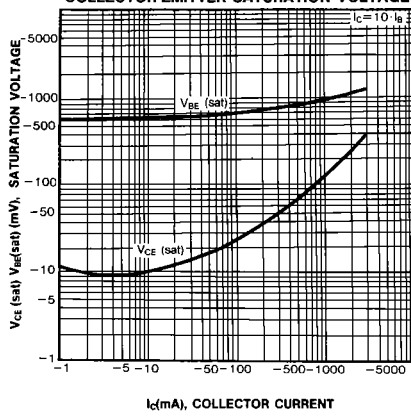
STATIC CHARACTERISTIC



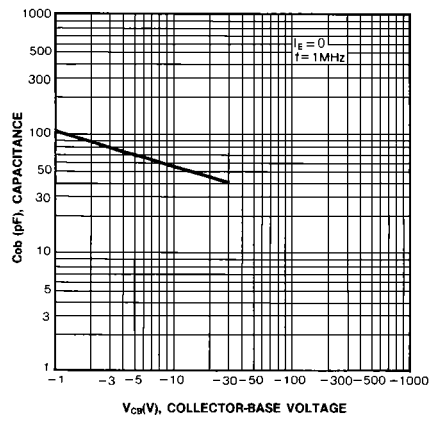
DC CURRENT GAIN



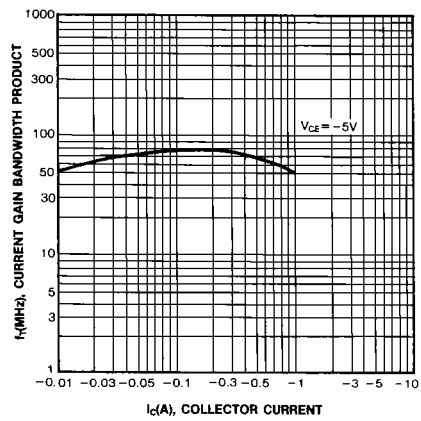
**BASE-EMITTER SATURATION VOLTAGE
COLLECTOR-EMITTER SATURATION VOLTAGE**



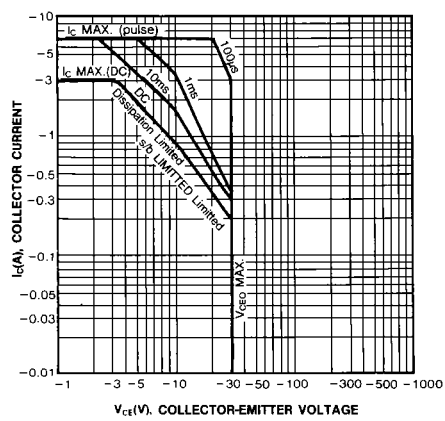
COLLECTOR OUTPUT CAPACITANCE



CURRENT GAIN-BANDWIDTH PRODUCT



SAFE OPERATING AREA



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